## Slotted Optical Switch

OPB818

## $T_{T}$ Electronics

## Features:

- Choice of aperture
- Choice of opaque or IR transmissive shell material
- Non-contact switching
- Mounts directly to PCBoard or dual-in-line socket
- $0.400^{\prime \prime}(10.16 \mathrm{~mm})$ lead spacing
- $0.200^{\prime \prime}(5.08 \mathrm{~mm})$ slot width. $0.250^{\prime \prime}(6.35 \mathrm{~mm})$ slot depth



## Description:

The OPB818 slotted switch consists of an infrared emitting diode and an NPN silicon phototransistor mounted in a low-cost black plastic housing on opposite sides of a 0.200 " ( 5.080 mm ) wide slot. Switching of the phototransistor occurs whenever an opaque object passes through the slot.

The OPB818 is designed for direct soldering into PCBoards or for mounting in standard dual-in-line sockets and has an $0.25^{\prime \prime}(6.35 \mathrm{~mm})$ deep and $0.20^{\prime \prime}(5.08 \mathrm{~mm})$ wide slot. The apertures are $0.033^{\prime \prime}(0.84 \mathrm{~mm})$ in diameter on both the sensor side (" S ") as well as on the emitter side (" E ").

## Applications:

- Non-contact object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety


| Ordering Information |  |
| :---: | :---: |
| Part <br> Number | Description |
| OPB818 | Slotted Optical Switch <br> (mounts directly to PCBoards <br> or to dual-in-line socket) |


| Pin \# | Description | Pin \# | Description |
| :---: | :---: | :---: | :---: |
| 1 | Anode | 4 | Collector |
| 2 | Cathode | 3 | Emitter |



## Electrical Specifications

## Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Storage \& Operating Temperature Range | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| :--- | ---: |
| Lead Soldering Temperature $[1 / 16 \text { inch }(1.6 \mathrm{~mm}) \text { from the case for } 5 \text { sec. with soldering iron }]^{(1)}$ | $260^{\circ} \mathrm{C}$ |

Input Diode

| Forward DC Current | 50 mA |
| :--- | ---: |
| Peak Forward Current $(1 \mu \mathrm{~s}$ pulse width, 300 pps$)$ | 1 A |
| Power Dissipation $^{(2)}$ | 75 mW |

## Output Phototransistor

| Collector-Emitter Voltage | 30 V |
| :--- | ---: |
| Emitter-Collector Voltage | 5 V |
| Collector DC Current | 30 mA |
| Power Dissipation ${ }^{(2)}$ | 100 mW |

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |

Input Diode (see OP240 for additional information)

| $\mathrm{V}_{\mathrm{F}}$ | Forward Voltage | - | - | 1.7 | V | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| :--- | :--- | :---: | :---: | :---: | :---: | :--- |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current | - | - | - | - | Not designed for reverse operation |

Output Phototransistor (see OP550 for additional information)

| $\mathrm{V}_{\text {(BR/(CEO) }}$ | Collector-Emitter Breakdown Voltage | 30 | - | - | V | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ |
| :---: | :--- | :---: | :---: | :---: | :---: | :--- |
| $\mathrm{~V}_{\text {(BR)/(ECO) }}$ | Emitter-Collector Breakdown Voltage | 5 | - | - | V | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}$ |
| $\mathrm{I}_{\text {CEO }}$ | Collector-Emitter Leakage Current | - | - | 100 | nA | $\mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0, \mathrm{E}_{\mathrm{E}}=0$ |

Coupled

| $\mathrm{I}_{\mathrm{C}(\mathrm{ON})}$ | On-State Collector Current | 100 | - | - | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |
| :---: | :--- | :---: | :---: | :---: | :---: | :--- |
| $\mathrm{~V}_{\mathrm{CE}(\text { SAT })}$ | Collector-Emitter Saturation Voltage | - | - | 0.4 | V | $\mathrm{I}_{\mathrm{C}}=50 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=20 \mathrm{~mA}$ |

(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
(2) Derate linearly $1.67 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
(3) All parameters were tested using pulse techniques.
(4) Leads are $0.20^{\prime \prime}$ square ( 5.080 mm ) and $0.425^{\prime \prime}$ long ( 10.80 mm ), minimum.
(5) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones. Spray and wipe; do not submerge.
(6) Polarity is denoted by color of housing top: LED (gray or clear), sensor (black).
(7) Do not apply reverse voltage to LED. LED will be a $O \mathrm{~V}$ in reverse voltage and draw current as if a short.

## Performance




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